DATA SHEET

Solid State Relay OCMOS FET

PS7141-1A,PS7141L-1A

6-PIN DIP, 400V BREAK DOWN VOLTAGE 1-ch Optical Coupled MOS FET

DESCRIPTION

NEC

The PS7141-1A and PS7141L-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7141L-1A has a surface mount type lead.

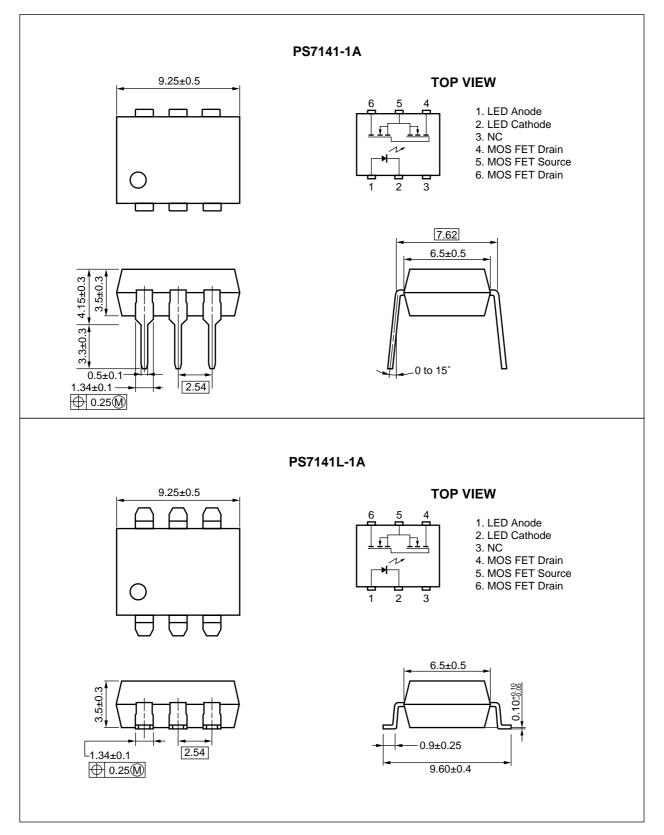
★ FEATURES

- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS7141L-1A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

PACKAGE DIMENSIONS (in millimeters)



***** ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS7141-1A	6-pin DIP	Magazine case 50 pcs	PS7141-1A
PS7141L-1A			PS7141L-1A
PS7141L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7141L-1A-E4			

*1 For the application of the Safety Standard, following part number should be used.

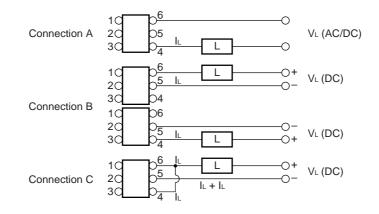
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	Parameter			Ratings	Unit
Diode	Forward Current (DC)		lf	50	mA
	Reverse Voltage		Vr	5.0	V
	Power Dissipation		PD	50	mW
	Peak Forward Current		IFP	1	А
MOS FET	Break Down Voltage		VL	400	V
	Continuous	Connection A	IL.	150	mA
	Load Current ^{*2}	Connection B		200	
		Connection C		300	
	Pulse Load Current ^{*3} (AC/DC Connection)		Ilp	300	mA
	Power Dissipation		PD	560	mW
Isolation Voltage ^{*4}			BV	1 500	Vr.m.s.
Total Power Dissipation		P⊤	610	mW	
Operating Ambient Temperature			TA	-40 to +80	°C
Storage Te	Storage Temperature			-40 to +100	°C

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

*1 PW = 100 μ s, Duty Cycle = 1 %

*2 Conditions: IF \geq 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

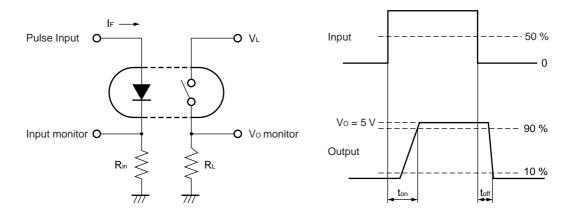
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP. MAX.		Unit	
LED Operating Current	lF	2	10	20	mA	
LED Off Voltage	VF	0		0.5	V	

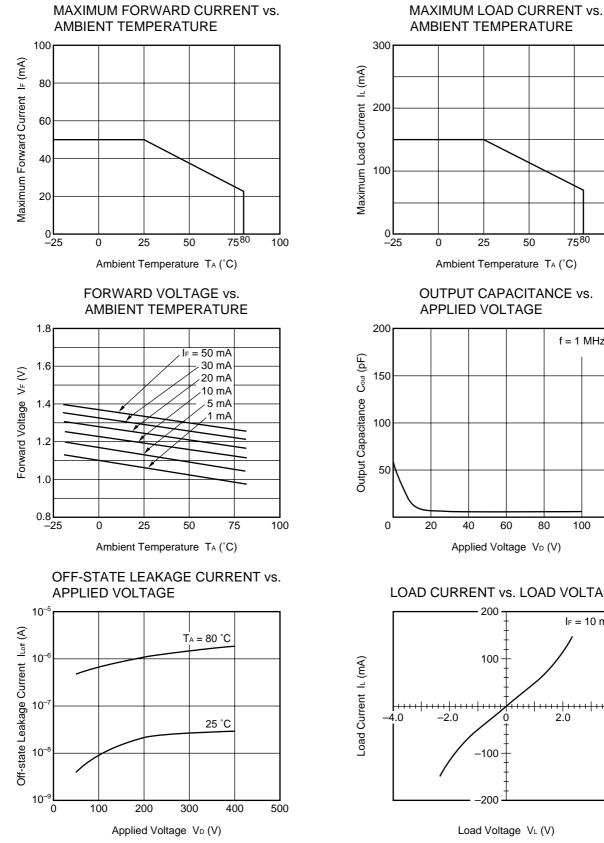
***** ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	de Forward Voltage		IF = 10 mA		1.2	1.4	V
	Reverse Current	Ir	V _R = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	V _D = 400 V		0.03	1.0	μA
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		65		pF
Coupled	LED On-state Current	IFon	l∟ = 150 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		20	30	Ω
		Ron2	I_F = 10 mA, I_L = 150 mA, t \leq 10 ms		16	25	
	Turn-on Time ^{⁺1}	ton	I_{F} = 10 mA, Vo = 5 V, PW \geq 10 ms		0.35	1.0	ms
	Turn-off Time [™]	toff			0.06	0.2	
	Isolation Resistance	Ri-o	VI-O = 1.0 kVDC	10 [°]			Ω
	Isolation Capacitance	CI-0	V = 0 V, f = 1 MHz		1.1		pF

*1 Test Circuit for Switching Time



TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



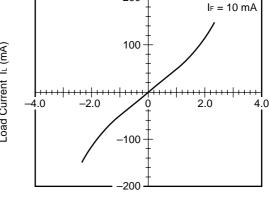
60 80 100 120 Applied Voltage VD (V) LOAD CURRENT vs. LOAD VOLTAGE 200

50

75⁸⁰

f = 1 MHz

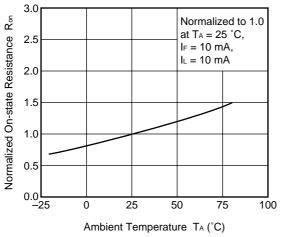
100



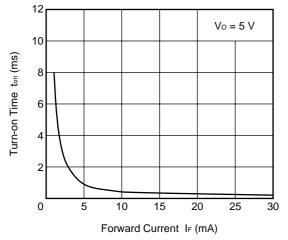
Load Voltage VL (V)

Data Sheet P11557EJ8V0DS00

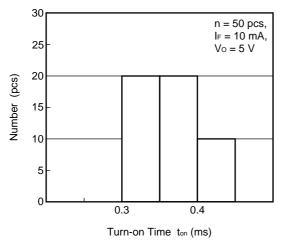
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



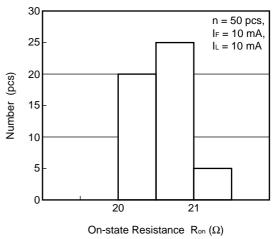
TURN-ON TIME vs. FORWARD CURRENT



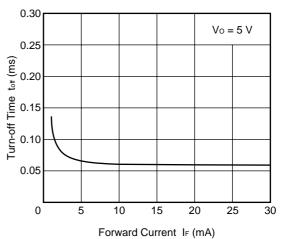
TURN-ON TIME DISTRIBUTION



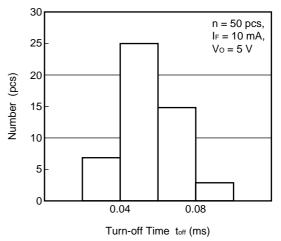
ON-STATE RESISTANCE DISTRIBUTION

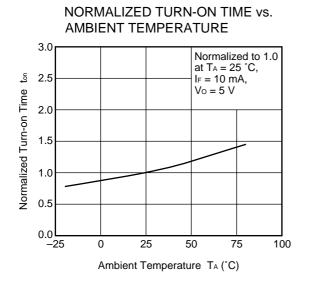


TURN-OFF TIME vs. FORWARD CURRENT

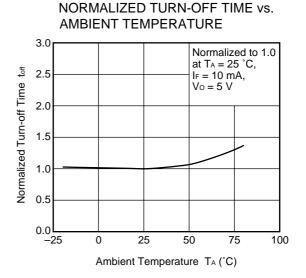


TURN-OFF TIME DISTRIBUTION

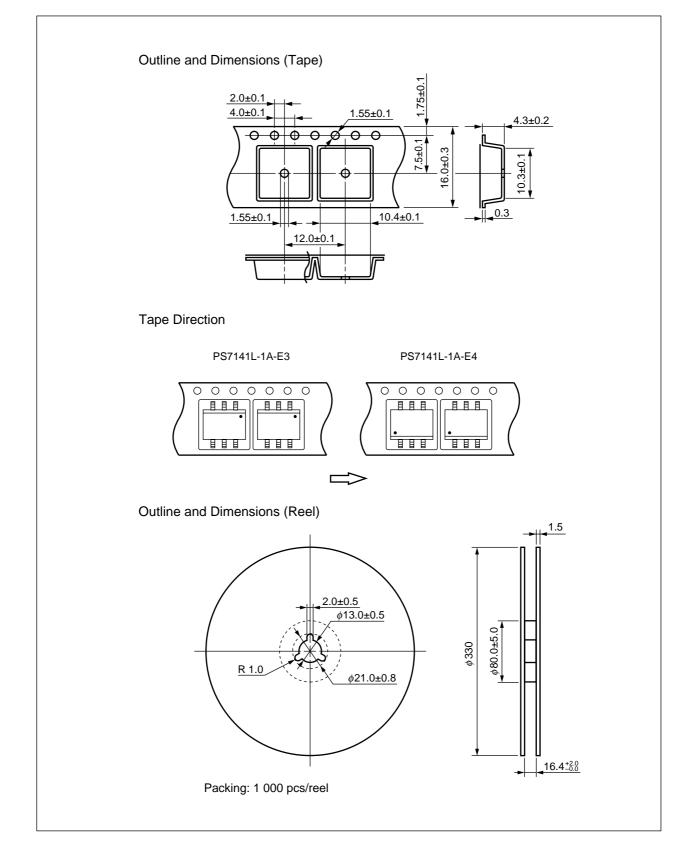




Remark The graphs indicate nominal characteristics.



***** TAPING SPECIFICATIONS (in millimeters)



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

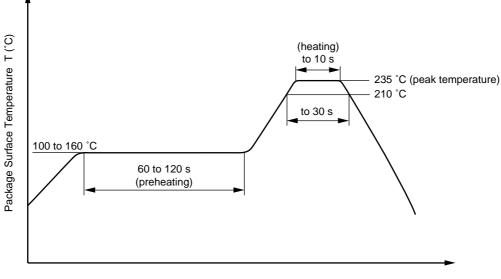
- Peak reflow temperature 235 °C (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

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Two Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow

30 seconds or less





(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

- Time
 - e 10 seconds or less nber of times One
- Number of times
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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